NSN 5961-00-079-6951

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-079-6951 **Inclosure Material:** Metal **Overall Length:** 0.400 inches **Overall Diameter:** 0.562 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 peak positive gate voltage **Current Rating Per Characteristic:** 3.00 amperes forward current, total rms blank **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Special Features:** Internal junction configuration, pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0